SCBS689H - MAY 1997 - REVISED OCTOBER 2003

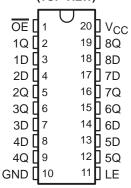
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Support Unregulated Battery Operation Down to 2.7 V
- I_{off} and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

description/ordering information

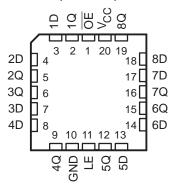
These octal latches are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

SN54LVTH373 . . . J OR W PACKAGE SN74LVTH373 . . . DB, DW, NS, OR PW PACKAGE (TOP VIEW)



SN54LVTH373 . . . FK PACKAGE (TOP VIEW)



A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

ORDERING INFORMATION

TA	PACK	(AGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	0010 014	Tube	SN74LVTH373DW	L\/TLI070
	SOIC - DW	Tape and reel	SN74LVTH373DWR	LVTH373
-40°C to 85°C	SOP - NS	Tape and reel	SN74LVTH373NSR	LVTH373
-40°C to 85°C	SSOP – DB	Tape and reel	SN74LVTH373DBR	LXH373
	TCCOD DW	Tube SN74LVTH373PV		LXH373
	TSSOP – PW	Tape and reel	SN74LVTH373PWR	LXH3/3
	CDIP – J	Tube	SNJ54LVTH373J	SNJ54LVTH373J
–55°C to 125°C	CFP – W	Tube	SNJ54LVTH373W	SNJ54LVTH373W
	LCCC - FK	Tube	SNJ54LVTH373FK	SNJ54LVTH373FK

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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description/ordering information (continued)

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

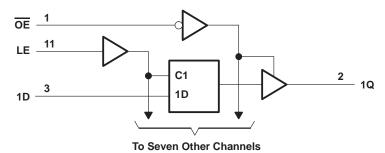
Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

FUNCTION TABLE (each latch)

	INPUTS		OUTPUT
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q ₀
Н	Χ	Χ	Z

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	
or power-off state, V _O (see Note 1)	′ to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)0.5 V to V _{CC}	
Current into any output in the low state, IO: SN54LVTH373	96 mA
SN74LVTH373 1	28 mA
Current into any output in the high state, I _O (see Note 2): SN54LVTH373	48 mA
SN74LVTH373	64 mA
Input clamp current, I_{IK} ($V_I < 0$)	-50 mA
Output clamp current, I_{OK} ($V_O < 0$)	-50 mA
Package thermal impedance, θ _{JA} (see Note 3): DB package	'0°C/W
DW package 5	8°C/W
NS package 6	0°C/W
PW package 8	
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			SN54LV	TH373	SN74LV	TH373	
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		2.7	3.6	2.7	3.6	V
VIH	High-level input voltage		2		2		V
V _{IL}	Low-level input voltage			0.8		8.0	V
VI	Input voltage			5.5		5.5	V
loн	High-level output current			-24		-32	mA
loL	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200		200		μs/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

				SN5	4LVTH37	3	SN74	LVTH37	3	
PARA	METER	TEST Co	ONDITIONS	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT
VIK		V _{CC} = 2.7 V,	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0.2			V _{CC} -0.2			
V		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4			V
VOH		V 2 V	$I_{OH} = -24 \text{ mA}$	2						V
		VCC = 3 V	$I_{OH} = -32 \text{ mA}$				2			
		Vaa – 2.7.V	I _{OL} = 100 μA			0.2			0.2	
		V _{CC} = 2.7 V	I _{OL} = 24 mA			0.5			0.5	
V			I _{OL} = 16 mA			0.4			0.4	V
VOL		V _{CC} = 3 V	$I_{OL} = 32 \text{ mA}$			0.5			0.5	V
		vCC = 2 v	$I_{OL} = 48 \text{ mA}$			0.55				
			$I_{OL} = 64 \text{ mA}$						0.55	
		$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V			10			10	
l _l	Control inputs	V _{CC} = 3.6 V,	$V_I = V_{CC}$ or GND			±1			±1	μА
	Data		$V_I = V_{CC}$			1			1	
	inputs	V _{CC} = 3.6 V	V _I = 0		-5		-5			
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V						±100	μΑ
		V _{CC} = 3 V	V _I = 0.8 V	75			75			
I _I (hold)	Data	vCC = 3 v	V _I = 2 V	-75			-75			μΑ
i(iioia)	inputs	$V_{CC} = 3.6 V^{\ddagger},$	$V_{I} = 0 \text{ to } 3.6 \text{ V}$						500 -750	
lozh		$V_{CC} = 3.6 \text{ V},$	V _O = 3 V			5			5	μΑ
lozL		$V_{CC} = 3.6 \text{ V},$	$V_0 = 0.5 \text{ V}$			-5			-5	μΑ
IOZPU		$\frac{V_{CC}}{OE} = 0$ to 1.5 V, $V_{O} = 0$	0.5 V to 3 V,			±100*			±100	μΑ
IOZPD		$\frac{\text{V}_{C}\text{C}}{\text{OE}} = 1.5 \text{ V to } 0, \text{ V}_{O} = 0$	0.5 V to 3 V,			±100*			±100	μА
		V _{CC} = 3.6 V,	Outputs high			0.19			0.19	
ICC		$I_{O} = 0$,	Outputs low			5			5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19			0.19	
ΔICC§		V _{CC} = 3 V to 3.6 V, On Other inputs at V _{CC} or			_	0.2		_	0.2	mA
Ci		V _I = 3 V or 0			3			3		pF
Co		V _O = 3 V or 0			7			7		pF

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C. ‡ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

[§] This is the increase in supply current for each input that is at the specified TTL voltage level, rather than VCC or GND.

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			SN54L\	/TH373			SN74L\	/TH373		
			3.3 V 3 V	VCC =	2.7 V	V _{CC} =	3.3 V 3 V	VCC =	2.7 V	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _W	Pulse duration, LE high	3		3		3		3		ns
t _{su}	Setup time, data before LE↓	1.1		0.4		1.1		0.4		ns
t _h	Hold time, data after LE↓	1.7		2		1.4		1.4		ns

switching characteristics over recommended free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

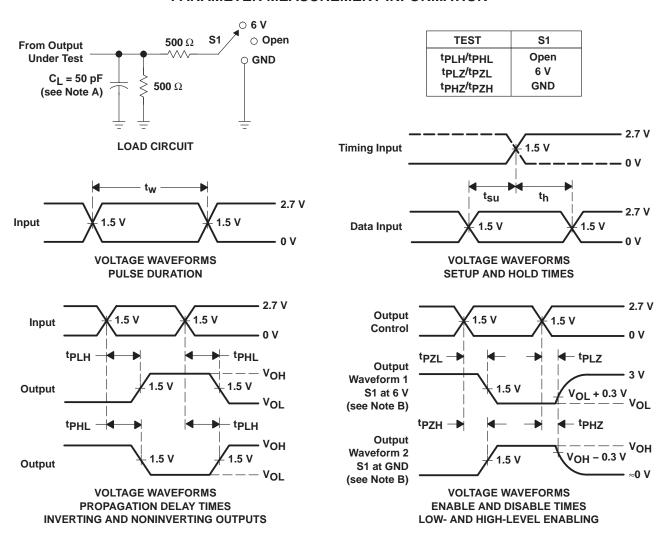
				SN54L\	/TH373			SN7	4LVTH	373			
PARAMETER	FROM (INPUT)	_		V_{CC} = 3.3 V \pm 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V			V _{CC} = 2.7 V		
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX		
^t PLH	-	_	1.4	4.1		4.7	1.5	2.6	3.9		4.5		
^t PHL	D	Q	1.4	4.1		4.7	1.5	2.6	3.9		4.5	ns	
^t PLH	LE	_	1.6	4.4		5.1	1.7	2.7	4.2		4.9		
^t PHL	LE	Q	1.6	4.4		5.1	1.7	2.7	4.2		4.9	ns	
^t PZH	ŌĒ	0	1.2	5		6.1	1.3	3	4.8		5.9	20	
tPZL	OE	Q	1.2	5		5.7	1.3	3	4.8		5.5	ns	
^t PHZ	ŌĒ	0	1.6	5.5		5.7	1.9	3	4.6		4.9	20	
t _{PLZ}	OE .	Q	0.8	4.8		4.9	1.9	3	4.5		4.6	ns	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \ \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9950901Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9950901Q2A SNJ54LVTH 373FK	Samples
5962-9950901QRA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950901QR A SNJ54LVTH373J	Samples
5962-9950901QSA	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950901QS A SNJ54LVTH373W	Samples
SN74LVTH373DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH373	Samples
SN74LVTH373DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH373	Samples
SN74LVTH373DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH373	Samples
SN74LVTH373NSR	ACTIVE	SOP	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH373	Samples
SN74LVTH373PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH373	Samples
SN74LVTH373PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH373	Samples
SN74LVTH373PWRE4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH373	Samples
SN74LVTH373PWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH373	Samples
SNJ54LVTH373FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9950901Q2A SNJ54LVTH 373FK	Samples
SNJ54LVTH373J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950901QR A SNJ54LVTH373J	Samples
SNJ54LVTH373W	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9950901QS A SNJ54LVTH373W	Samples



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(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54LVTH373, SN74LVTH373:

Catalog: SN74LVTH373

Enhanced Product: SN74LVTH373-EP, SN74LVTH373-EP

Military: SN54LVTH373



PACKAGE OPTION ADDENDUM

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NOTE: Qualified Version Definitions:

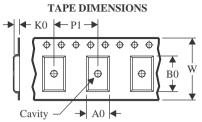
- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH373DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH373DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVTH373NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVTH373PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1



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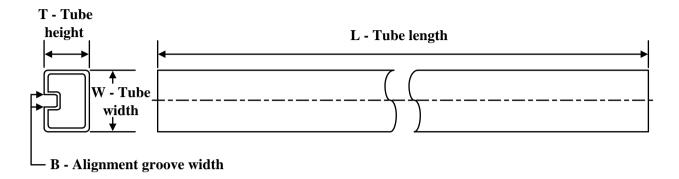
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH373DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LVTH373DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH373NSR	SOP	NS	20	2000	367.0	367.0	45.0
SN74LVTH373PWR	TSSOP	PW	20	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9950901Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74LVTH373DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVTH373PW	PW	TSSOP	20	70	530	10.2	3600	3.5
SNJ54LVTH373FK	FK	LCCC	20	55	506.98	12.06	2030	NA





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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